## NSN 5961-01-329-4370

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-329-4370 **Inclosure Material:** Plastic **Overall Length:** Between 12.45 millimeters and 15.24 millimeters **Terminal Length:** Between 6.23 millimeters and 19.30 millimeters **Overall Diameter:** Between 36.07 millimeters and 43.18 millimeters **Function For Which Designed:** Rectifier **End Application:** Forrestal class cv, ticonderoga class cg (47), oliver perry class ffg, spruance class dd (963), kidd class ddg, arleigh burke class ddg, nimitz class cvn. Landing craft air cushion (lcac). Tf33-pw-102 aircraft engine (c-135e, ec-135h/k/p). Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-200 **Mounting Method: Terminal Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 repetitive peak reverse voltage and 0.9 forward voltage, dc **Current Rating Per Characteristic:** 150.00 amperes forward current, average preset and 20.00 amperes forward current, average absolute **Special Features:** Weapon system essential; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: